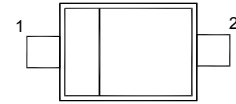


**FEATURES**

- Low Forward Voltage Drop.
- Guard Ring Construction For Transient Protection.
- Negligible Reverse Recovery Time.
- Low Reverse Capacitance.


 1.Cathode  
 2.Anode

**Simplified outline(SOD-323S)**
**APPLICATIONS**

- Schottky barrier switching.

**Top View** 
**MAXIMUM RATING @ Ta=25°C unless otherwise specified**

Parameter	Symbol	1N5819WS	1N5819BWS	1N5819CWS	Unit
Peak Repetitive Peak reverse voltage	$V_{RR}$				
Working Peak DC Reverse Voltage	$V_{RWM}$	40	30	20	V
	$V_R$				
RMS Reverse Voltage	$V_{R(RMS)}$	28	21	14	V
Forward Continuous Current	$I_F$	350			mA
Repetitive Peak Forward Current @t≤1.0s	$I_{FRM}$	1.5			A
Power Dissipation	$P_d$	400			mW
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	300			°C/W
Storage temperature	$T_{stg}$	-65~+125			°C

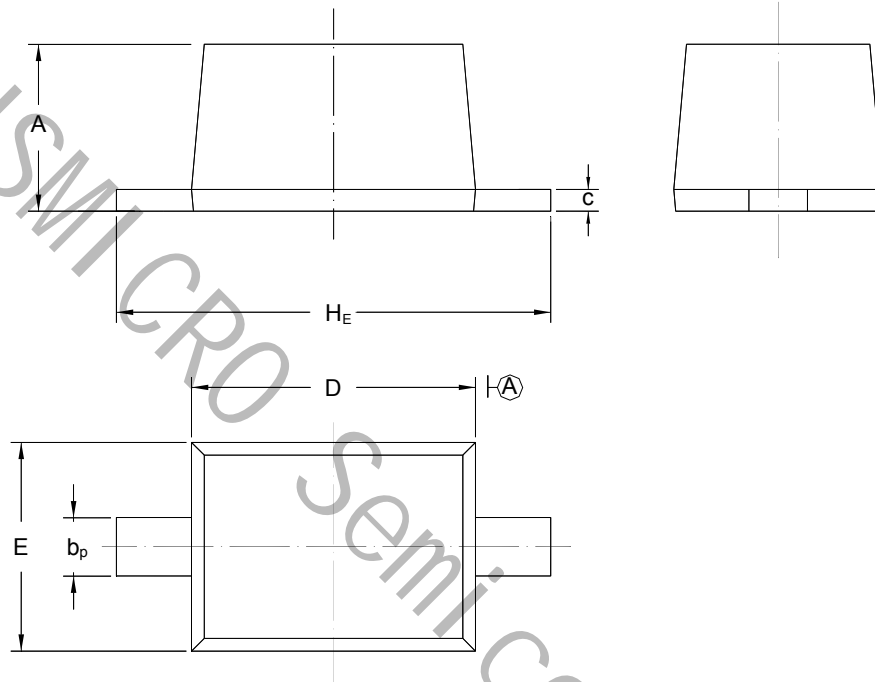
**ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Reverse Breakdown Voltage	$V_{(BR)R}$	40			V	$I_R=10\mu A$
		30				$I_R=10\mu A$
		20				$I_R=10\mu A$
Forward voltage	$V_F$			0.37 0.60	V	$I_F=20mA$ $I_F=200mA$
Reverse current	$I_{RM}$			5.0	$\mu A$	$V_R=30V$ $V_R=20V$ $V_R=10V$
Capacitance between terminals	$C_T$		50		pF	$V_R=0, f=1MHz$
Reverse Recovery Time	$t_{rr}$		10		ns	$I_R=I_F=200mA$ $I_{rr}=0.1 \cdot I_R, R_L=100\Omega$

**Marking**

NO.	1N5819WS	1N5819BWS	1N5819CWS
Marking	S4	S5	S6

## ■ SOD-323S



UNIT	A	b <sub>p</sub>	C	D	E	H <sub>E</sub>
mm	1.10 0.80	0.40 0.25	0.15 0.10	1.80 1.60	1.35 1.15	2.80 2.30

## ■ The recommended mounting pad size

